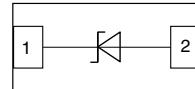


ESD Protection Diode in DFN1006

Features

- 1680 Watts peak pulse power ($T_p = 8/20\mu s$)
- DFN1006 package
- Uni-directional configurations
- Low clamping voltage
- Low leakage current
- Normal capacitance ($C_J = 110\text{pF}$ typ.)
- Protection one data/power line to:
IEC 61000-4-2 ±30kV contact ±30kV air
IEC 61000-4-4 (EFT) 40A (5/50ns)
IEC 61000-4-5 (Lightning) 70A (8/20μs)



Mechanical Data

- **Case:** DFN1006 (plastic package).
Lead free; RoHS compliant; Halogen free
- **Molding Compound Flammability Rating:**
UL 94 V-0
- **Terminals:** High temperature soldering guaranteed:
260 °C/10 sec. at terminals

Applications

- Microprocessor based equipment
- Personal Digital Assistants (PDAs)
- Notebooks & Handhelds
- Portable Instrumentation
- Digital Cameras
- Portable Instrumentation

Absolute Maximum Ratings

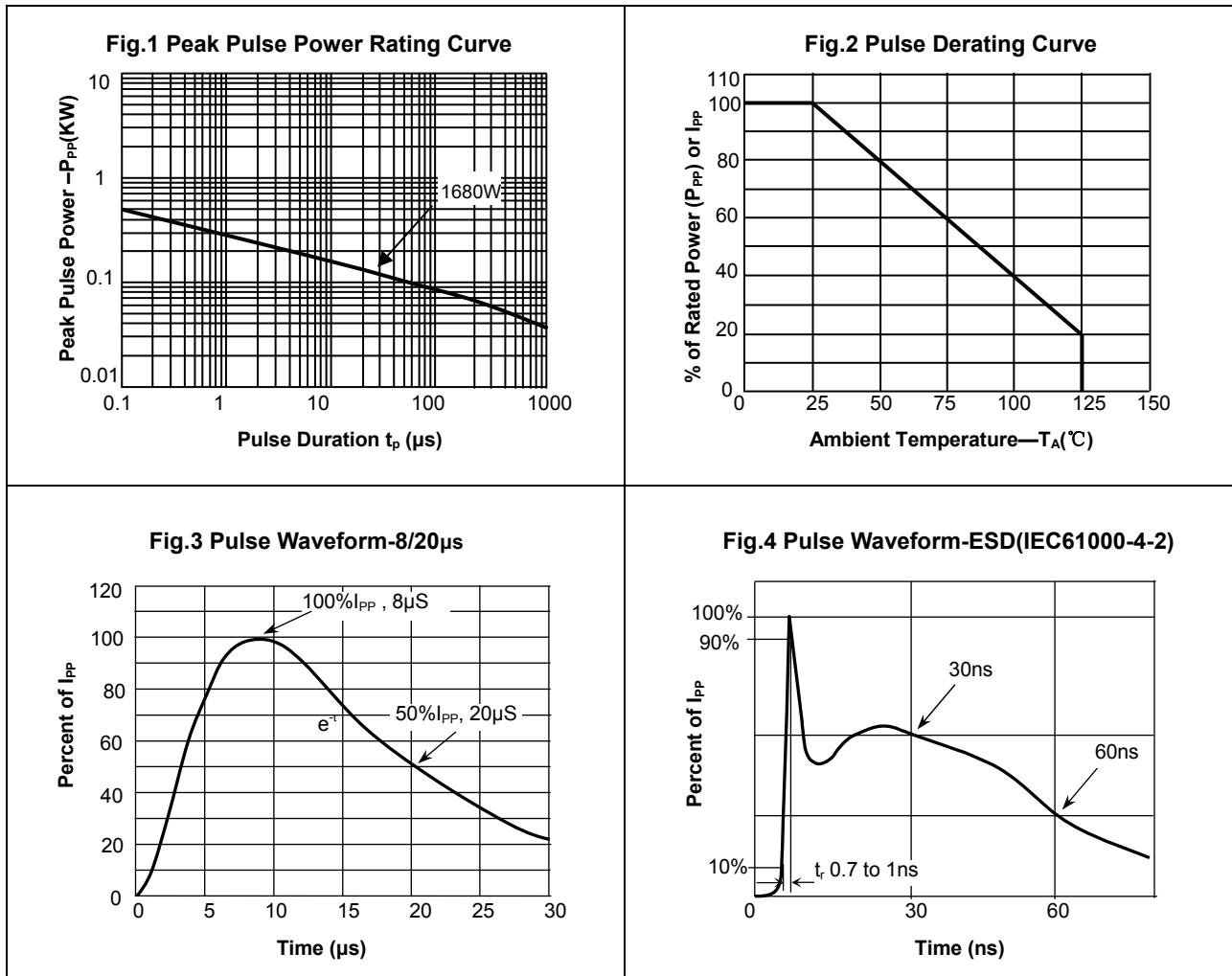
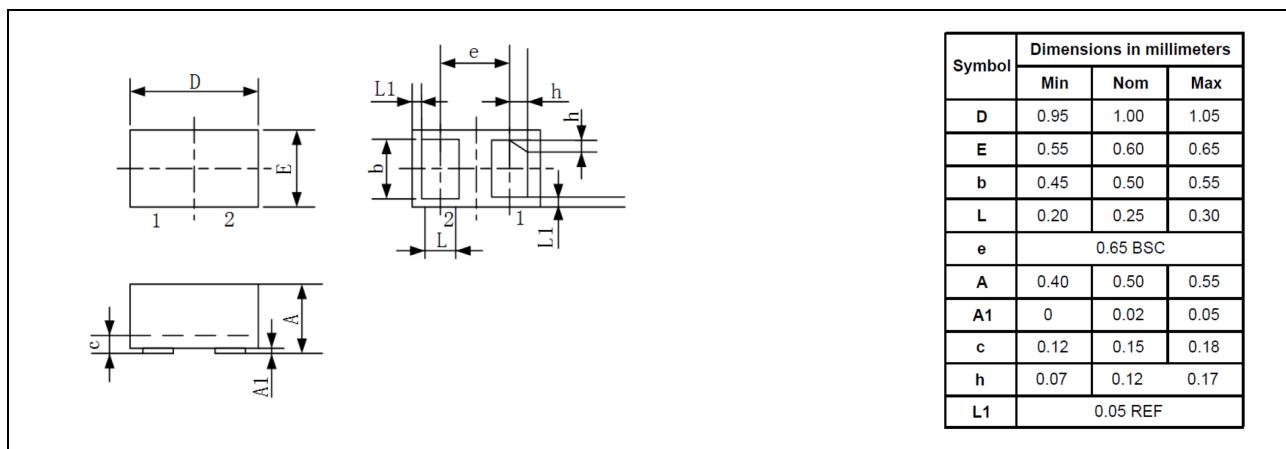
Ratings at 25 °C, ambient temperature unless otherwise specified

Parameter	Symbol	Value	Unit
Peak Pulse Power ($T_p=8/20\mu s$)	P_{PP}	1680	W
ESD contact/air discharge (IEC-61000-4-2)	V_{ESD}	30/30	kV
Peak Pulse Current ($T_p = 8/20\mu s$)	I_{PP}	70	A
Junction Temperature	T_J	-55 to +125	°C
Storage temperature	T_{STG}	-55 to +150	°C

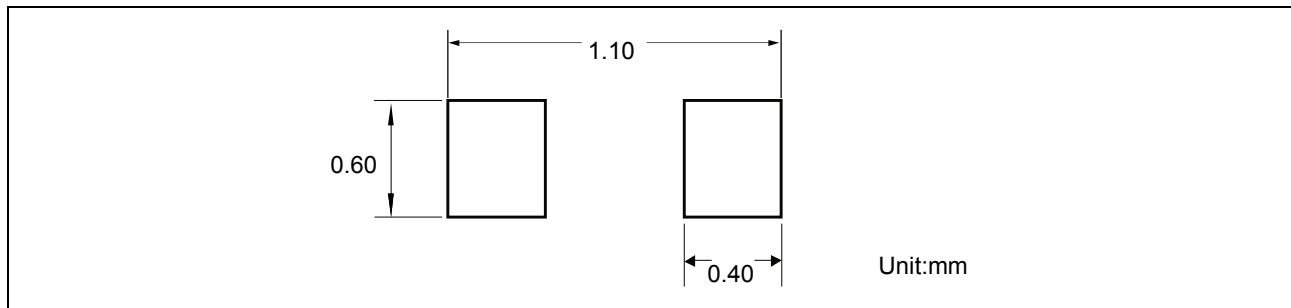
Electrical Characteristics

($T_A = 25$ °C unless otherwise specified)

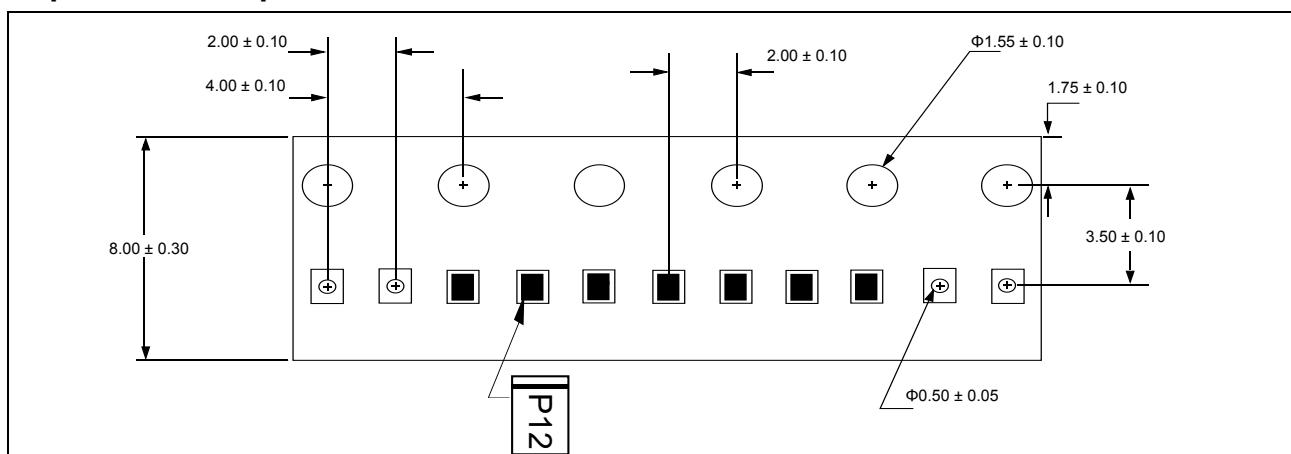
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Reverse stand-off Voltage	V_{RWM}				12.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$	13.3			V
Reverse Leakage Current	I_R	$V_{RWM}=12\text{V}$			0.5	uA
Clamping Voltage (IEC 61000-4-5)	V_C	$I_{PP}=70\text{A}$		24		V
Junction Capacitance	C_J	$V_R=0\text{V}, f=1\text{MHz}$		110		pF

Typical Characteristics ($T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified)

Package Dimensions


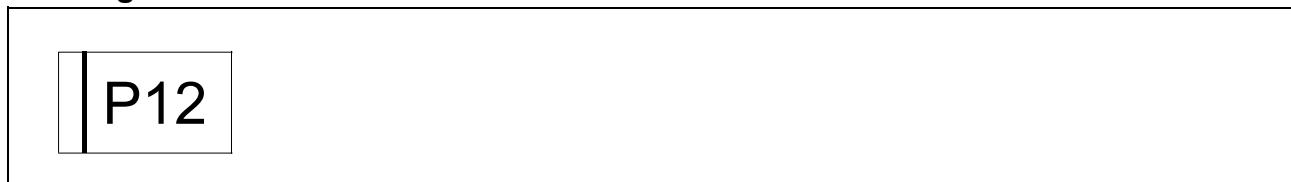
Pad Dimensions



Tape and Reel Specification



Marking



Ordering information

Order code	Package	Packaging option	Base quantity	Packaging specification
TESD1006HC12VUH	DFN1006	Tape and reel	10000pcs / reel	EIA STD RS-481